

Vishay High Power Products

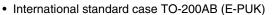
Phase Control Thyristors (Hockey PUK Version), 960 A

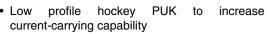


TO-200AB (E-PUK)

r	EA	U	NE	3

- · Center amplifying gate
- · Metal case with ceramic insulator





- Lead (Pb)-free
- Designed and qualified for industrial level



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PRODUCT SUMMARY				
I _{T(AV)}	960 A			

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		960	A		
$I_{T(AV)}$	T _{hs}	55	°C		
I _{T(RMS)}		1900	A		
	T _{hs}	25	°C		
I _{TSM}	50 Hz	15 000	^		
	60 Hz	15 700	A		
124	50 Hz	1130	kA ² s		
l ² t	60 Hz	1030	KA-S		
V _{DRM} /V _{RRM}		400/600	V		
t _q	Typical	100	μs		
T _J		- 40 to 125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= T_{J} & \text{MAXIMUM} \\ \text{mA} \end{aligned}$			
ST380CC	04	400 500		50			
0100000	06	600	700	30			

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ST380CPbF Series



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PARAMETER	SYMBOL		TEST CONDITIONS			
Maximum average on-state current	1	180° conduc	180° conduction, half sine wave double side (single side) cooled		960 (440)	Α
at heatsink temperature	$I_{T(AV)}$	double side			55 (75)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	1900	
		t = 10 ms	No voltage		15 000	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		15 700	Α
non-repetitive surge current	I _{TSM}			12 600	1	
			13 200]		
Marrian no 19h fau fraign		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	1130	- kA ² s
	l ² t	t = 8.3 ms	reapplied		1030	
Maximum I ² t for fusing	127	t = 10 ms	100 % V _{RRM}		800	
		t = 8.3 ms	reapplied		725	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10	ms, no voltage	reapplied	11 300	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	x I _{T(AV)} < I < π x	$I_{T(AV)}$, $T_J = T_J$ maximum	0.85	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$			m O
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.24	mΩ
Maximum on-state voltage	V_{TM}	$I_{pk} = 3000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			1.60	V
Maximum holding current	I _H	T 05 °C	T 05:00		600	A
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load			1000	mA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0			
Typical turn-off time	tq	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs		

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs			
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	50	mA			



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TRIGGERING						
DADAMETED	CVMDOL	TEST CONDITIONS		VALUES		UNITS
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	10	0.0	w
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T - T movimum	t < 5 ma	20		V
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms			5.0	
	T _J = - 40 °C		200	-		
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Maximum required gate trigger/	100	200	mA
		T _J = 125 °C	current/voltage are the lowest	50	-	
		T _J = - 40 °C	value which will trigger all units		-	
DC gate voltage required to trigger	V _{GT}	$T_J = 25 ^{\circ}C$	12 V anode to cathode applied	1.8	3.0	V
		T _J = 125 °C		1.1	-	
DC gate current not to trigger	I _{GD}	T - T movimum	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V _{GD}	$T_J = T_J$ maximum	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.	25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	T_J		- 40 to 125	- °C	
Maximum storage temperature range	T _{Stg}		- 40 to 150	C	
Maximum thormal registance, junction to heataink	D	DC operation single side cooled	0.09		
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.04	K/W	
Maximum thermal resistance, case to heatsink	В	DC operation single side cooled	0.02	TV/VV	
Maximum thermal resistance, case to heatslink	R _{thC-hs}	DC operation double side cooled	0.01		
Mounting force, ± 10 %			9800 (1000)	N (kg)	
Approximate weight			83	g	
Case style		See dimensions - link at the end of datasheet	TO-200AB (E	E-PUK)	

△R _{thJ-hs} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL	USOIDAL CONDUCTION RECTANGULAR CONDU		R CONDUCTION	TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.010	0.011	0.007	0.007			
120°	0.012	0.012	0.012	0.013	$T_J = T_J$ maximum		
90°	0.015	0.015	0.016	0.017		K/W	
60°	0.022	0.022	0.023	0.023			
30°	0.036	0.036	0.036	0.037			

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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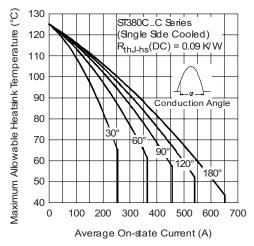


Fig. 1 - Current Ratings Characteristics

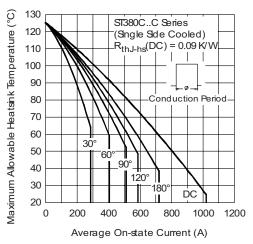


Fig. 2 - Current Ratings Characteristics

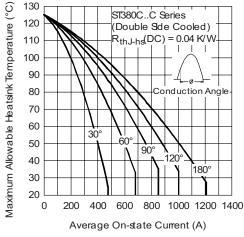


Fig. 3 - Current Ratings Characteristics

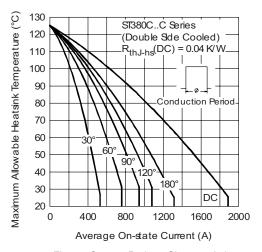


Fig. 4 - Current Ratings Characteristics

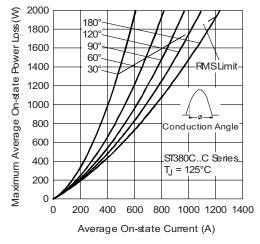


Fig. 5 - On-State Power Loss Characteristics

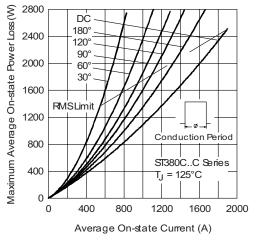


Fig. 6 - On-State Power Loss Characteristics



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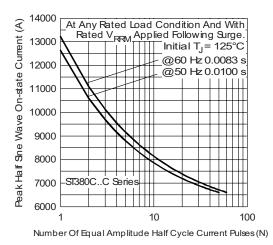


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

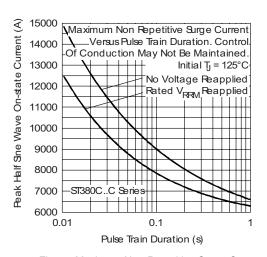


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

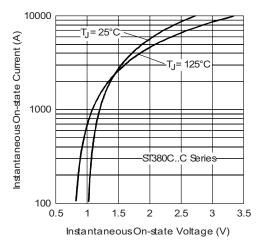


Fig. 9 - On-State Voltage Drop Characteristics

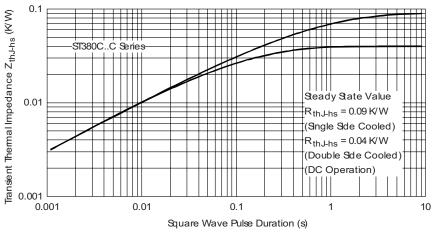


Fig. 10 - Thermal Impedance $Z_{thJ\text{-}hs}$ Characteristics

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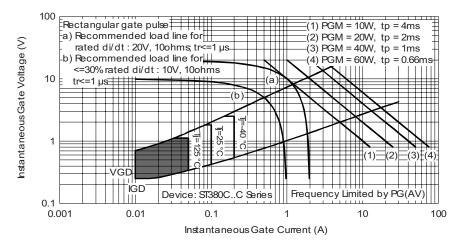
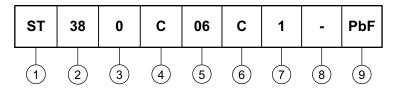


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Thyristor
- Essential part number
- 0 = Converter grade
- 4 C = Ceramic PUK
- Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 6 C = PUK case TO-200AB (E-PUK)
- 7 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)
 - 1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)
 - 2 = Eyelet terminals (gate and auxiliary cathode soldered leads)
 - 3 = Fast-on terminals (gate and auxiliary cathode soldered leads)
- 8 Critical dV/dt: None = 500 V/µs (standard selection)
 - L = 1000 V/μs (special selection)
- 9 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95075			

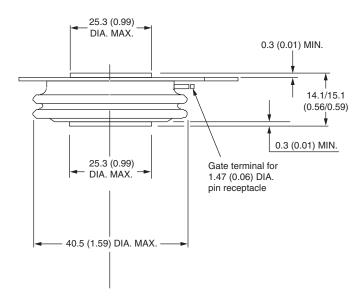
Vishay Semiconductors

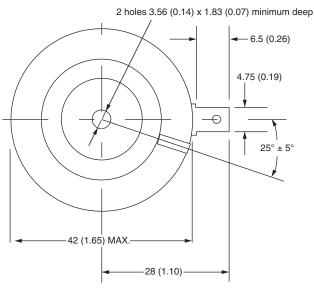
TO-200AB (E-PUK)

DIMENSIONS in millimeters (inches)

Anode to gate

Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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